Low-Voltage CMOS 18-Bit Universal Bus Transceiver

With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX16501 is a high performance, non–inverting 18–bit universal bus transceiver operating from a 2.7 to 3.6V supply. This part is not byte controlled; it is "18–bit" controlled. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V $_{\rm I}$ specification of 5.5V allows MC74LCX16501 inputs to be safely driven from 5V devices. The MC74LCX16501 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

<u>Dat</u>a flow in each direction is controlled by Output Enable (OEAB, OEBA), Latch Enable (LEAB, LEBA) and Clock inputs (CAB, CBA). When LEAB is HIGH, the A-to-B dataflow is transparent. When LEAB is LOW, and CAB is held at LOW or HIGH, the data A is latched; on the LOW-to-HIGH transition of CAB the A-data is stored in the latch/flip-flop. The outputs are active when OEAB is HIGH. When OEAB is LOW the B-outputs are in 3-state. Similarly, the LEBA, OEBA and CBA control the B-to-A dataflow. Please note that the output enables are complementary; OEAB is active HIGH, OEBA is active LOW.

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- Designed for 2.7 to 3.6V V_{CC} Operation
- 6ns t_{pd} Maximum
- 5V Tolerant Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When VCC = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (20μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

MC74LCX16501



LOW-VOLTAGE CMOS 18-BIT UNIVERSAL BUS TRANSCEIVER



DT SUFFIX 56-LEAD PLASTIC TSSOP PACKAGE CASE 1202-01

PIN NAMES

REV 1

Pins	Function
OEAB, OEBA CAB, CBA LEAB, LEBA A0-A17 B0-B17	Output Enable Inputs Clock Pulse Inputs Latch Enable Inputs Side A Inputs/Outputs Side B Inputs/Outputs



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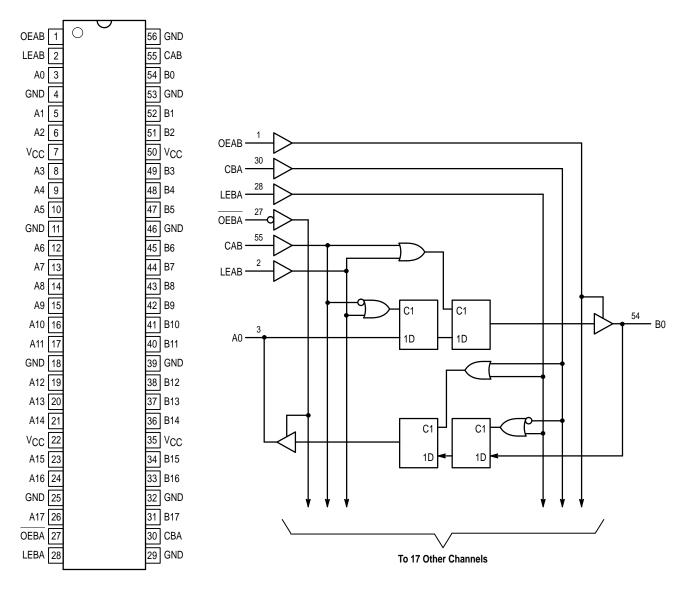


Figure 1. 56-Lead Pinout (Top View)

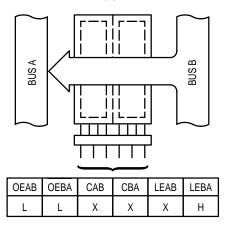
Figure 2. Logic Diagram

FUNCTION TABLE

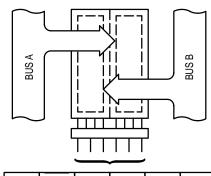
		Inp	uts			Da Po	ıta rts	Operating Mode
OEAB	OEBA	LEAB	LEBA	CAB	СВА	An	Bn	
L	Н					Input	Input	
				H or L	H or L	Х	Х	Hold Data; A and B Outputs Disabled
		L	L	1	1	l h	l h	Clock A and/or B Data; A and B Outputs Disabled
Н	Н					Input	Output	
				H or L	X*	Х	QA	Hold and Display B Data
		L	Х	1	X*	l h	L H	Clock A Data to B Bus; Store A Data
		Н	Х	х	X*	L H	L H	A Data to B Bus; (Transparent)
L	L					Output	Input	
				X*	H or L	QB	Х	Hold and Display A Data
		Х	L	X*	↑	L H	l h	Clock B Data to A Bus; Store B Data
		Х	Н	X*	Х	L H	L H	B Data to A Bus; (Transparent)
Н	L					Output	Output	
		L	L	H or L	H or L	QB	QA	Stored A Data to B Bus; Stored B Data to A Bus

H = High Voltage Level; L = Low Voltage Level; h = High Voltage Level One Setup Time Prior to the Latch Enable or Clock Low–to–High Transition; I = Low Voltage Level One Setup Time Prior to the Latch Enable or Clock Low–to–High Transition; X = Don't Care; ↑ = Low–to–High Clock Transition; QA = A input storage register; QB = B input storage register; * = The clocks are not internally gated with either the Output Enables or the Source Inputs. Therefore, data at the A or B ports may be clocked into the storage registers, at any time. For I_{CC} reasons, Do Not Float Inputs.

Real Time Transfer – Bus B to Bus A

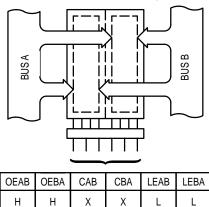


Store Data from Bus A, Bus B or Bus A and Bus B

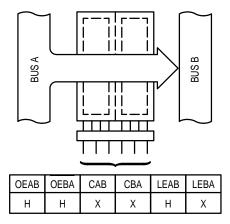


OEAB	OEBA	CAB	CBA	LEAB	LEBA
ΥL	п×н	↑ X X	X ↑ X	L X L	X L L

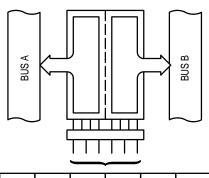
Store Bus A in Both Registers or Store Bus B in Both Registers



Real Time Transfer – Bus A to Bus B

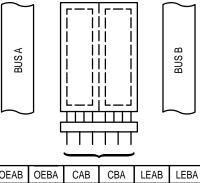


Transfer A Stored Data to Bus B or B Stored Data to Bus A or Both at the Same Time



$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	OEAB	OEBA	CAB	CBA	LEAB	LEBA
H L Horl Horl L L	H L H	H L L	↑ X H or L	X ↑ H or L	L X L	X L L

Isolation



OEAB	OEBA	CAB	CBA	LEAB	LEBA
L	Н	H or L	H or L	L	L

Figure 3. Bus Applications

L

L

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
Vcc	DC Supply Voltage	−0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_1 \le +7.0$		V
Vo	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3-State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
lık	DC Input Diode Current	-50	V _I < GND	mA
loк	DC Output Diode Current	-50	V _O < GND	mA
		+50	AO > ACC	mA
lo	DC Output Source/Sink Current	±50		mA
Icc	DC Supply Current Per Supply Pin	±100		mA
^I GND	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

^{*} Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied.

1. Output in HIGH or LOW State. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
Vcc	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
Vo	Output Voltage (HIGH or LOW State) (3–State)	0 0		V _{CC} 5.5	V
IOH	HIGH Level Output Current, V _{CC} = 3.0V – 3.6V			-24	mA
lOL	LOW Level Output Current, V _{CC} = 3.0V – 3.6V			24	mA
loн	HIGH Level Output Current, V _{CC} = 2.7V – 3.0V			-12	mA
lOL	LOW Level Output Current, V _{CC} = 2.7V – 3.0V			12	mA
TA	Operating Free–Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V_{IN} from 0.8V to 2.0V, $V_{CC} = 3.0V$	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = -40°C	T _A = -40°C to +85°C	
Symbol	Characteristic	Condition	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage (Note 2.)	$2.7V \le V_{CC} \le 3.6V$	2.0		V
V _{IL}	LOW Level Input Voltage (Note 2.)	$2.7V \le V_{CC} \le 3.6V$		0.8	V
Vон	HIGH Level Output Voltage	$2.7V \le V_{CC} \le 3.6V; I_{OH} = -100\mu A$	V _{CC} – 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -12mA$	2.2		
		$V_{CC} = 3.0V; I_{OH} = -18mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -24mA$	2.2		
VOL	LOW Level Output Voltage	$2.7V \le V_{CC} \le 3.6V; I_{OL} = 100 \mu A$		0.2	V
		$V_{CC} = 2.7V; I_{OL} = 12mA$		0.4	
		$V_{CC} = 3.0V; I_{OL} = 16mA$		0.4	
		$V_{CC} = 3.0V; I_{OL} = 24mA$		0.55	

^{2.} These values of V_I are used to test DC electrical characteristics only.

DC ELECTRICAL CHARACTERISTICS (continued)

			T _A = -40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
lį	Input Leakage Current	$2.7V \le V_{CC} \le 3.6V; \ 0V \le V_{I} \le 5.5V$		±5.0	μΑ
loz	3–State Output Current	$2.7 \le V_{CC} \le 3.6V$; $0V \le V_{O} \le 5.5V$; $V_{I} = V_{IH}$ or V_{IL}		±5.0	μΑ
loff	Power-Off Leakage Current	$V_{CC} = 0V$; V_I or $V_O = 5.5V$		10	μΑ
ICC	Quiescent Supply Current	$2.7 \le V_{CC} \le 3.6V$; $V_I = GND$ or V_{CC}		20	μΑ
		$2.7 \le V_{CC} \le 3.6V$; $3.6 \le V_{I}$ or $V_{O} \le 5.5V$		±20	μΑ
Δlcc	Increase in I _{CC} per Input	$2.7 \le V_{CC} \le 3.6V$; $V_{IH} = V_{CC} - 0.6V$		500	μΑ

AC CHARACTERISTICS (Note 3.; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 500 \Omega$)

				Lin	nits		
				T _A = -40°	C to +85°C		1
			V _{CC} = 3.	0V to 3.6V	V _{CC} :	= 2.7V	1
Symbol	Parameter	Waveform	Min	Max	Min	Max	Unit
f _{max}	Maximum Clock Frequency	3	170				MHz
^t PHL ^t PLH	Propagation Delay Input to Output	1	1.5 1.5	6.0 6.0	1.5 1.5	7.0 7.0	ns
tPHL tPLH	Propagation Delay Clock to Output	3	1.5 1.5	6.7 6.7	1.5 1.5	8.0 8.0	ns
tPHL tPLH	Propagation Delay LExx to Output	4	1.5 1.5	7.0 7.0	1.5 1.5	8.0 8.0	ns
^t PZH ^t PZL	Output Enable Time to High and Low Level	2	1.5 1.5	7.2 7.2	1.5 1.5	8.2 8.2	ns
^t PHZ ^t PLZ	Output Disable Time From High and Low Level	2	1.5 1.5	7.0 7.0	1.5 1.5	8.0 8.0	ns
t _S	Setup Time	3,4	2.5		2.5		ns
th	Hold Time	3,4	1.5		1.5		ns
t _W	Pulse Width Time	3,4	3.0		3.0		ns
tOSHL tOSLH	Output-to-Output Skew (Note 4.)			1.0 1.0			ns

DYNAMIC SWITCHING CHARACTERISTICS

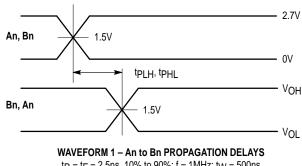
			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
VOLP	Dynamic LOW Peak Voltage (Note 5.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V
V _{OLV}	Dynamic LOW Valley Voltage (Note 5.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V

^{5.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

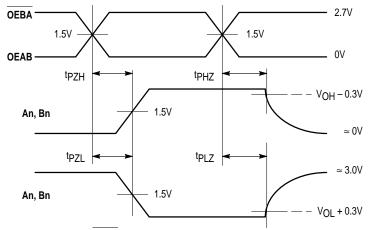
These AC parameters are preliminary and may be modified prior to release.
 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.
 The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter
 guaranteed by design.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	20	pF



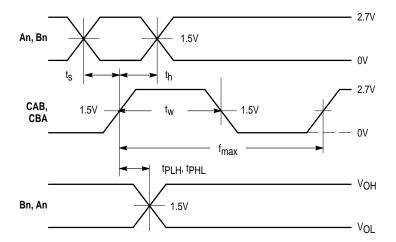
 $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz; $t_W = 500$ ns



WAVEFORM 2 – OEBA/OEAB to An/Bn OUTPUT ENABLE AND DISABLE TIMES $t_R=t_F=2.5 ns,\ 10\%\ to\ 90\%;\ f=1MHz;\ t_W=500 ns$

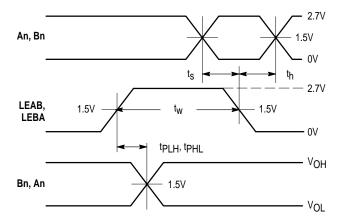
Figure 4. AC Waveforms

7



WAVEFORM 3 – CLOCK to Bn/An PROPAGATION DELAYS, CLOCK MINIMUM PULSE WIDTH, An/Bn to CLOCK SETUP AND HOLD TIMES

 $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz; $t_W = 500$ ns except when noted



WAVEFORM 4 – LEXX to An, Bn PROPAGATION DELAYS, LEXX MINIMUM PULSE WIDTH, An, Bn to LEXX SETUP AND HOLD TIMES

 $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz; $t_W = 500$ ns except when noted

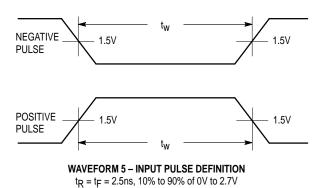
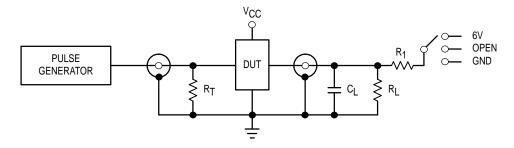


Figure 5. AC Waveforms (continued)



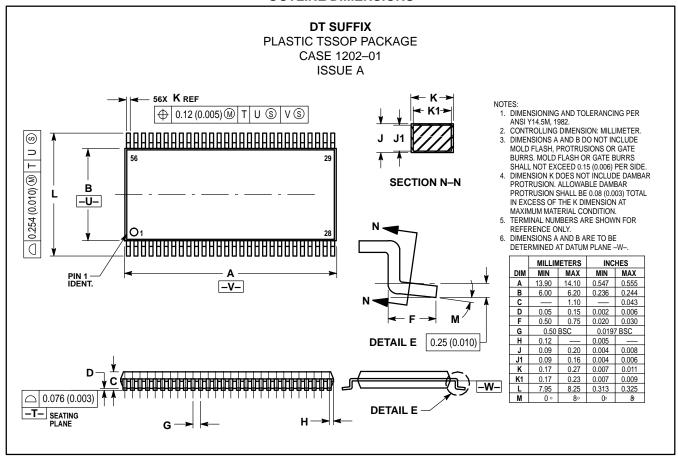
TEST	SWITCH
tPLH, tPHL	Open
t _{PZL} , t _{PLZ}	6V
Open Collector/Drain tpLH and tpHL	6V
tPZH, tPHZ	GND

 C_L = 50pF or equivalent (Includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 6. Test Circuit

9

OUTLINE DIMENSIONS



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